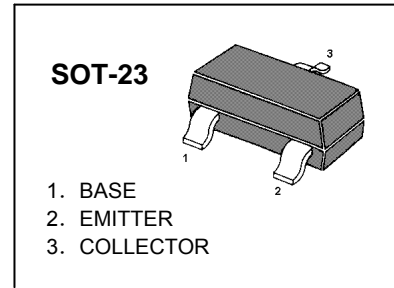


TRANSISTOR (NPN)

FEATURES

Switching transistor

MARKING: 2X



MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CB0}	Collector-Base Voltage	60	V
V_{CE0}	Collector-Emitter Voltage	40	V
V_{EB0}	Emitter-Base Voltage	6	V
I_C	Collector Current -Continuous	600	mA
P_C	Collector Power dissipation	0.3	W
T_j	Junction Temperature	150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-55to +150	$^{\circ}\text{C}$
$R_{\theta JA}$	Thermal Resistance, junction to Ambient	357	$^{\circ}\text{C}/\text{mW}$

ELECTRICAL CHARACTERISTICS ($T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\mu\text{A}$, $I_E=0$	60		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}$, $I_B=0$	40		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu\text{A}$, $I_C=0$	6		V
Collector cut-off current	I_{CBO}	$V_{CB}=50\text{V}$, $I_E=0$		0.1	μA
Collector cut-off current	I_{CEO}	$V_{CE}=30\text{V}$, $I_B=0$		0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=5\text{V}$, $I_C=0$		0.1	μA
DC current gain	h_{FE}	$V_{CE}=1\text{V}$, $I_C=150\text{mA}$	100	300	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=150\text{mA}$, $I_B=15\text{mA}$		0.4	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=150\text{mA}$, $I_B=15\text{mA}$		0.95	V
Transition frequency	f_T	$V_{CE}=10\text{V}$, $I_C=20\text{mA}$ $f=100\text{MHz}$	250		MHz

Typical Characteristics

MMBT4401

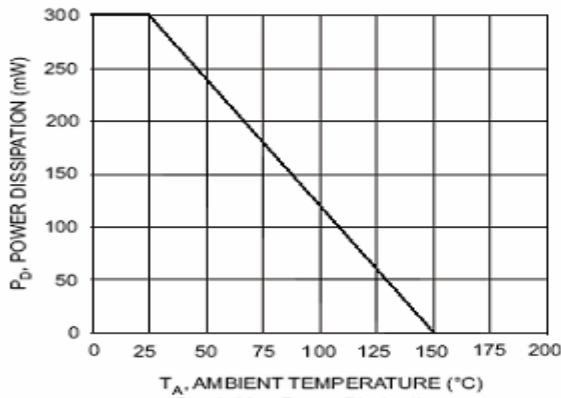


Fig. 1 Max Power Dissipation vs Ambient Temperature

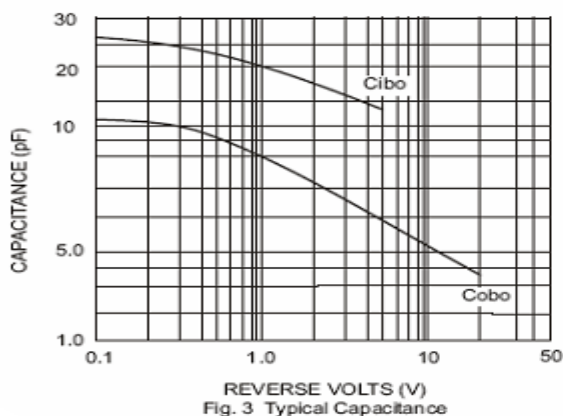


Fig. 3 Typical Capacitance

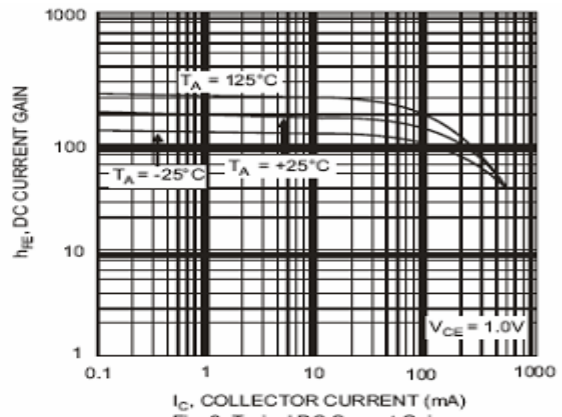


Fig. 2 Typical DC Current Gain vs Collector Current

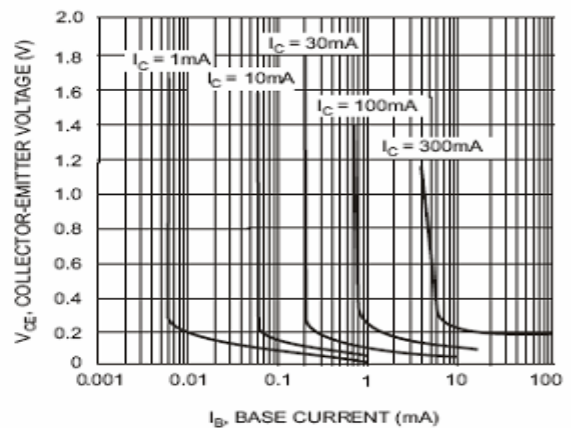


Fig. 4 Typical Collector Saturation Region

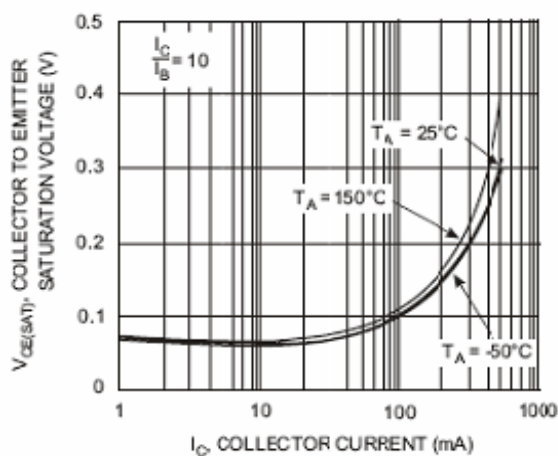


Fig. 5 Collector Emitter Saturation Voltage vs. Collector Current

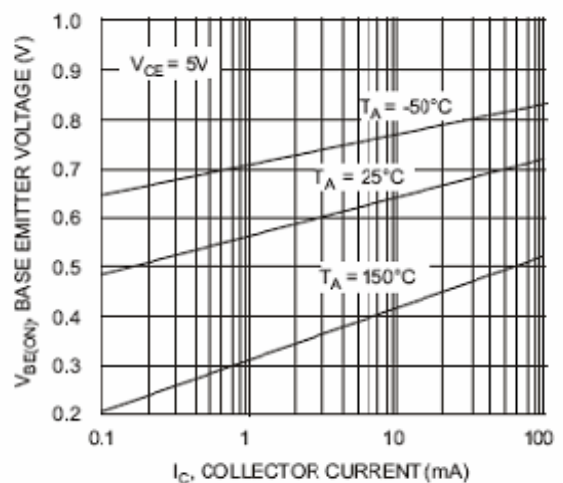


Fig. 6 Base Emitter Voltage vs. Collector Current

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

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